## NSN 5961-01-604-8225

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-604-8225 **Inclosure Material:** Metal **Overall Length:** 6.540 inches **Overall Height:** 1.360 inches **Overall Width:** 5.910 inches **End Application:** 6130-01-573-8037 **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon carbide Voltage Rating In Volts Per Characteristic: 1200.0 collector-to-emitter voltage, instantaneous **Current Rating Per Characteristic:** 1400.0 amperes emitter current, dc **Product Name:** Module, igbt **Terminal Type And Quantity:** 9 threaded hole Shelf Life: N/a **Unit Of Measure:** 

Demilitarization:

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